

Green University of Bangladesh (GUB) Dept. of Computer Science and Engineering



COURSE OUTLINE

1	Faculty	Faculty of S	Science and Engineering	(FSE)							
2	Department	CSE									
3	Programme	B.Sc in CS	E								
4	Name of	Electronic l	Electronic Devices and Circuits & Pulse Techniques								
	Course										
5	Course Code	EEE 203	EEE 203								
6	Trimester	Fall, 2021	Fall, 2021								
7	Pre-requisites	EEE 201 (C	CSE)								
8	Status	Other Engin	neering Course								
9	Credit Hours	3									
10	Section	201 DH, 20	02 DA, 202 DB								
11	Class Hours	Section	Class Day	Class Hours	Venue						
		201 DH	Tuesday	03:00-04:30 PM	Zoom						
			Thursday	08:30-10:00 AM	Zoom						
		202 DA	Tuesday	01:30-03:00 PM	Zoom						
			Thursday	01:30-03:00 PM	Zoom						
		202 DB	Tuesday	11:30 AM-1:00 PM 11:30 AM-1:00 PM	Zoom						
			Thursday	Zoom							
12	Class Location	Online									
13	Course	https://classi	coom.google.com/u/1/c/N	DA2MDAvOTUzODE2	[201DH]						
	website	_	coom.google.com/u/1/c/N	•							
		_	coom.google.com/u/1/c/N		=						
14	Instructor	Israt Jahan	Israt Jahan								
15	Contact	jahan@eee.	green.edu.bd								
16	Office	Desk-15, R	oom No: B-607								
17	Counselling	Day	Counseling Hours	Venue							
	Hours	Sunday	11.30 AM- 1.00 PM	online							

18	Text Books	1. Sedra A. S., Smith K. C., Microelectronic Circuits, fifth edition, Oxford
		university press 2. Coughlin, R. F., & Driscoll, F. F. (1987). Operational amplifiers and linear
		integrated circuits. Prentice-Hall, Inc.
		3. Alexander C. K., Sadiku M. N. O., Fundamentals of Electric Circuits, fourth edition, McGraw-Hill.
19	Reference	1. Millman, J., Halkias C. & Parikh C. D., Integrated Electronics: Analog and
	Books	Digital circuits and systems, 2 _{nd} edition, McGraw-Hill.
		2. Robert L. Boylestad & Louis Nashelsky. Electronic Devices and Circuit Theory.
		Prentice-Hall, Inc.
20	Equipment & Aids	Bring your own materials (calculator,pen, paper, etc.) to participate effectively in
		classroom activities.
		Besides class note, please keep at least one blank A4 size paper per class with you.
21	Course	This course will allow the students to learn about different types of electronic devices
	Rationale	and circuits and their applications.
22	Course	
	Description	Diode logic gates, transistor switches, transistor gates, MOS gates; Analog switches.
		Linear wave shaping: diode wave shaping techniques, clipping and clamping circuits, comparator circuits, switching circuits; Electronic circuits for flip-flops, counters and
		register, memory systems, PLA's; A/D and D/A converters with applications; Logic
		Families: TTL, ECL, IIL and CMOS logic with operation details; Propagation delay,
		product and noise immunity; Open collector and high impedance gates; S/H circuits,
		LED, LCD and optically coupled oscillators; Nonlinear applications of OP AMPs;
		Pulse transformers, pulse transmission, pulse generation; monostable, bi-stable and
		stable multi-vibrators, Schmitt trigger, blocking oscillators and time-base circuit;
		Timing circuits; Simple voltage sweeps, linear current sweeps. Device Problems including BJT, FET, MOSFETS, CMOS, TUBES, Digital interfaces including D/A,
		A/D, S/H. Digital Filters, Modern Sampling Techniques.
23	Course	After completing this course students will be able to
	Outcomes	CO1: Solve mathematical problems of various electronic components like diodes,
	(CO)	BJTs, FET, MOSFETs, OP-AMPs etc. [Cognitive]
		CO2: Describe the operation of various A/D and D/A converters, various pulse
		generating circuits with 555 timer IC, LED, LCD and PLA's. [Cognitive]
		CO3: Design various logic gates using CMOS technology, digital filters, TTL and
		ECL. [Affective]

24	Teaching Methods	Maximum topics will be covered from the topoks will be followed. White board will be multimedia projector will be used for the participate in classroom discussions for developments.	be used for most of convenience of	of the time. For the students. Stu	some cas	
25	Topic Outlin					
		d problems are from the main text if not specif		Curanata J	0-4	
	Lecture	Selected Topics	Article (Text)	Suggested Problems. (Text)	Outcom	
	(1)	Introduction to the course	-	-		
	(2-4)	Diode circuit models Solving mathematical problems with diode circuit	3.1, 3.3 (Text 1)	Related examples and problems from	CO1, CO2	
		models Diode Wave shaping (Clipping & Clamping) Diode logic gates	2.5 - 2.9 (Ref 2)	the book.		
		Introduction to OP-AMPs Non-linear applications of OP AMPs Transfer and providing Schwitt trip and circuit.	2.1 - 2.5 (Text 2)	Related examples and problems from	CO1, CO2	
		Inverting and non-inverting Schmitt trigger circuit Solving problems		the book.		
	(7-8)	memory systems	5.3 – 5.5 (Text 3)		CO1	
		Electronic circuits solving				
		Propagation delay, product and noise immunity Solving mathematical problems				
	(0.10)	Transfer of DYAN	5657	D 1 . 1	GO1	
	(9-10)	Introduction to PLA's,	5.6, 5.7, 6.6.1, 6.6.2	Related examples and	CO1,	
		Comparator circuits, A/D and D/A converters Logic Families: TTL, ECL and Monostable, bistable and stable multi-vibrators	(Text 3)	problems from the book.	CO3	
	(11-12)	Analog multiplier	4.2 - 4.4	Related	CO1,	
		Digital Filters Pulse transformers, pulse transmission, pulse generation	(Text 2)	examples and problems from the book.	CO2	
		Review on the topics covered before the mid-term examination.	1			
	(13-	Introduction to FET & MOSFETs				
,	(1)-	I minoduction to LET & MOSIETS				

	17)		asic operation of MOSFET's								4.3,	Related			CO2,	
			urrent voltage characteristics of MOSFET								3, 10.3		nples ar		CO	3
			S techn							(Tex	t 1)	problems from				
		Logic	Logic circuit design with CMOS technology											the book.		
	(18-	Introd	troduction to Bipolar Junction Transistors (BJT)							5.3.4	, 5.4,	Rela	ated		CO	2
	20)	Opera	perating modes of BJTs							5.5		exar	examples and			
		BJT a	T as a switch								t 1)	problems from				
		LED, I	D, LCD and optically coupled oscillators									the book.				
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	(21-23)										, 9.8.2,	Rela		1	CO3	3
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	-							Woons.		(162	ιι 1)	•	book.	OIII		
	-		le volta collect	-						13.1	-13.3,	the book.				
		Open	Conecu	or and	ı mgn	шреца	ince gai	es		13.5						
											kt 2)					
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	(24)	Revie	ew on th	ne topi	cs cov	ered be										
		exam	amination.													
26	Assessment															
	and Marks	1 -	quizzes, and class participation. Final numeric reward will be the compilation of (
	Distribution	: te	tentative):													
			❖ Class Tests (15%)													
								`								
					•	• Ass	signme	nt (5 %	6)							
					•	Ass	signme sentati	nt (5 % on (5 %	%) %)							
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27	Assessment	A	ssessm	ent m	* *	 Ass Pres Atte Mic Fins 	signme sentati endanc d-Term al Exa	on (5 % e and Test (40%)	%) Perfor (30%) %)		e (5 %))				
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	Methods of COs Mapping of	M	COs CO1 CO2 CO3	CT V	nethod	Ass Pre- Atto Mic Finals of Co	signme sentation endance d-Term al Exam Os are	ont (5 % on (5	(6) (8) (9) (9) (9) (10)	essme Γ F √ √ Os) ar	nt E As	signm				tion PO12
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29	Grading Policy	The folloguideline	_			·	_				from the	*
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		80 and above	75-<80	70-<75	65-<70	60-<65	55-<60	50-<55	45-<50	40-<45	<40	
29	Additional Course	Assign		No late l	homewo	rk will b	e accept	ed.			e counted	d.
	Policies		Γest Th Mid-ter	Two or assignment of assignment will can be to announce and firstrictly particularly synchronical entire the synchronical enti	more ents. Zeres to assibe at lear with ement. In all examples time	copied a ro tolerang ment past three h an ann will be d in exa	assignmence will problems CTs, besouncemented to closed am hall.	ents will be show s will be st of two ent in probook, c Please bours.	l carry n in this provide will be ior or wi losed no	regard. d on han counted. thout any tes. Cell ir own v	ark in a d. A CT y phone is vatch and	s d
		Test Policy: If you are absent from a test, and you have not spoken to the teach personally beforehand, your grade for the test will be zero. No make up for class test will be taken because it has alternative (three out four). No make-up for mid will be entertained without presence a recommendation of guardian and written permission of the department. Make-up test of mid will be much harder than the regular test.									No make- ree out of sence and n of the than the	f d e
30	Additional Information	b. Acad http:// c. Grad http://	dar. emic Inf //www.g ing and l //www.g	ormation reen.edu Performa reen.edu les: http:	n and Po .bd/acad ance Eva .bd/acad	licies: emics/ac luation: emics/ac	cademic-	rules-a-r	regulatio	ons.		